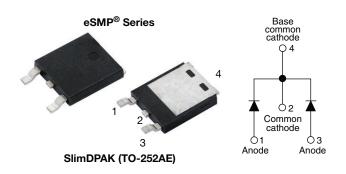
Vishay Semiconductors

Hyperfast Rectifier, 2 x 3 A FRED Pt[®]



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LINKS TO ADDITIONAL RESOURCES



SHAY

PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 3 A					
V _R	100 V				
V _F at I _F	0.75 V				
t _{rr} (typ.)	20 ns				
T _J max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configuration	Common cathode				

FEATURES

- · Hyperfast recovery time
- 175 °C operating junction temperature
- · Low forward voltage drop reduced Qrr and soft recovery
- Low leakage current
- Very low profile typical height of 1.3 mm
- Ideal for automated placement
- · Polyimide passivation for high reliability standard
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM R	ATINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage		V _{RRM}		100	V
Average rectified forward current	per leg	I	Total device, rated V_R , T_C = 166 °C	3	
Average rectilied forward current	per device	I _{F(AV)}		6	А
Non-repetitive peak surge current	per leg	I _{FSM}	T_J = 25 °C, 10 ms sine pulse wave	70	
Operating junction and storage ten	nperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	100	-	-		
		I _F = 3 A	-	0.9	1.04	v	
Forward voltage	VF	I _F = 3 A, T _J = 150 °C	-	0.75	0.82		
Forward voltage	vF	٧F	I _F = 6 A	-	1	1.2	
		I _F = 6 A, T _J = 150 °C	-	0.85	1.01		
De ser la la ser ser el la la la ser el la ser		V _R = V _R rated	-	-	5	•	
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	80	μA	
Junction capacitance	CT	V _R = 100 V	-	12	-	pF	

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RoHS COMPLIANT HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$	A/ μ s, V _R = 30 V	-	20	-		
Reverse recovery time	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R$	-	-	25			
Reverse recovery lime	t _{rr}	T _J = 25 °C		-	17	-	- ns - A	
		T _J = 125 °C		-	26	-		
Deels receiver a current		T _J = 25 °C	I _F = 3 A dI _F /dt = 200 A/μs V _B = 160 V	-	1.8	-		
Peak recovery current	I _{RRM}	T _J = 125 °C		-	3.2	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	15	-	nC	
		T _J = 125 °C		-	41	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾⁽²⁾		-	75	90	°C/W	
Thermal resistance, junction to mount, per leg	R _{thJM} ⁽³⁾		-	3.2	4	°C/W	
Marking device		Case style SlimDPAK (TO-252AE)		6CV	H01		

Notes

- ⁽¹⁾ The heat generated must be less than thermal conductivity from junction to ambient; $dP_D/dT_J < 1R_{thJA}$
- $^{(2)}$ Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} junction to ambient

⁽³⁾ Mounted on infinite heatsink

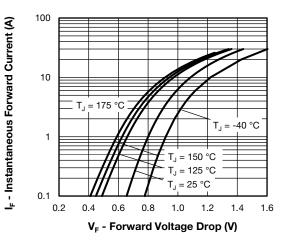


Fig. 1 - Typical Forward Voltage Drop Characteristics

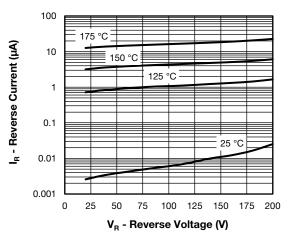


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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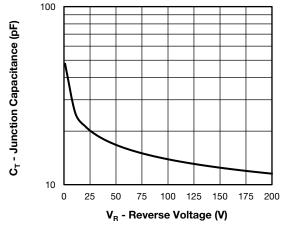


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

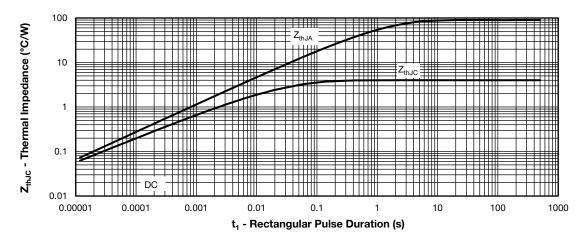
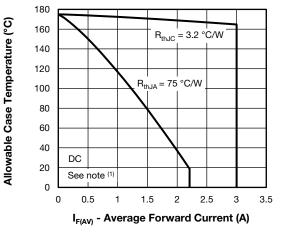
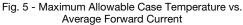


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

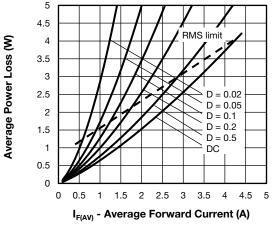


Fig. 6 - Forward Power Loss Characteristics

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3

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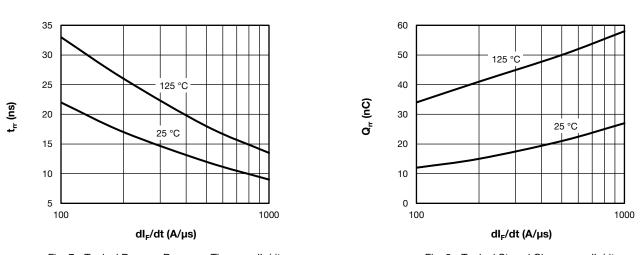


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

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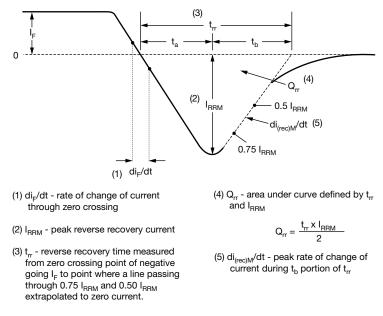


Fig. 9 - Reverse Recovery Waveform and Definitions

4

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ORDERING INFORMATION TABLE

VISHAY

Device code	VS-	6	с	v	н	01	-M3
		2	3	4	5	6	7
	1	- Visl	nay Sen	nicondu	ctors pro	oduct	
	2	- Cur	rent rati	ng (6 =	6 A)		
	3	- Circ	cuit conf	iguratior	n:		
		C =	commo	n catho	de		
	4	- V=	SlimDP	AK			
	5		cess typ				
			hyper fa		-		
			tage coo		,		
	7	- M3	= halog	en-free,	RoHS-0	complia	nt, and f

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	PACKAGING DESCRIPTION				
VS-6CVH01-M3/I	4500	4500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96081			
Part marking information	www.vishay.com/doc?96085			
Packaging information	www.vishay.com/doc?88869			

5

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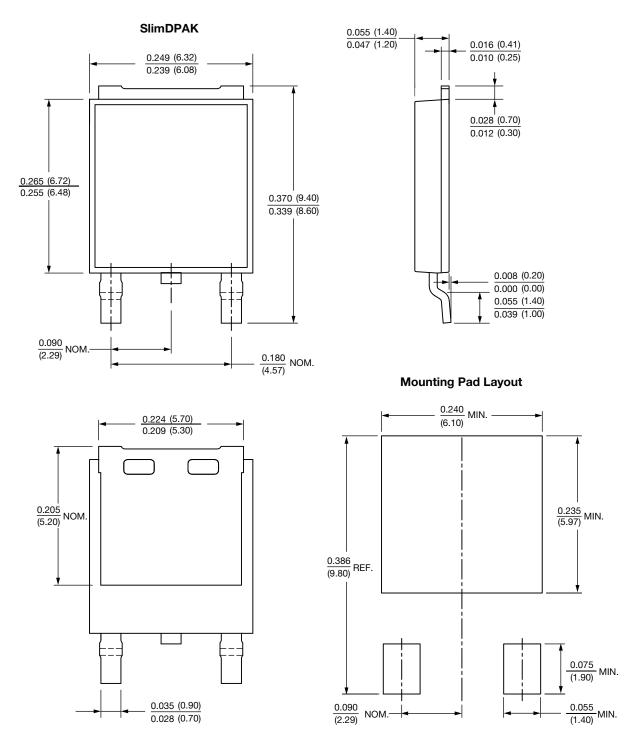


Outline Dimensions

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SlimDPAK

DIMENSIONS in inches (millimeters)





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